

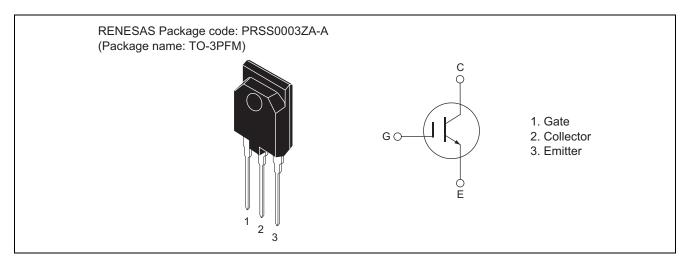
# RJP60V0DPM

600V - 22A - IGBT Application: Inverter R07DS0669EJ0200 Rev.2.00 Apr 02, 2014

### **Features**

- High breakdown-voltage
- Low Collector to Emitter saturation Voltage  $V_{CE(sat)} = 1.5 \text{ V}$  typ. (at  $I_C = 22 \text{ A}$ ,  $V_{GE} = 15 \text{ V}$ ,  $Ta = 25 ^{\circ}\text{C}$ )
- Short circuit withstand time (6 µs typ.)
- Trench gate and thin wafer technology (G6H series)

### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25°C	I <sub>C</sub>	45	Α
	Tc = 100°C	I <sub>C</sub>	22	Α
Collector peak current		I <sub>C(peak)</sub> Note1	90	Α
Collector dissipation		P <sub>C</sub> Note2		
Junction to case thermal impedance		θj-c Note2	3.125	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc = 25°C

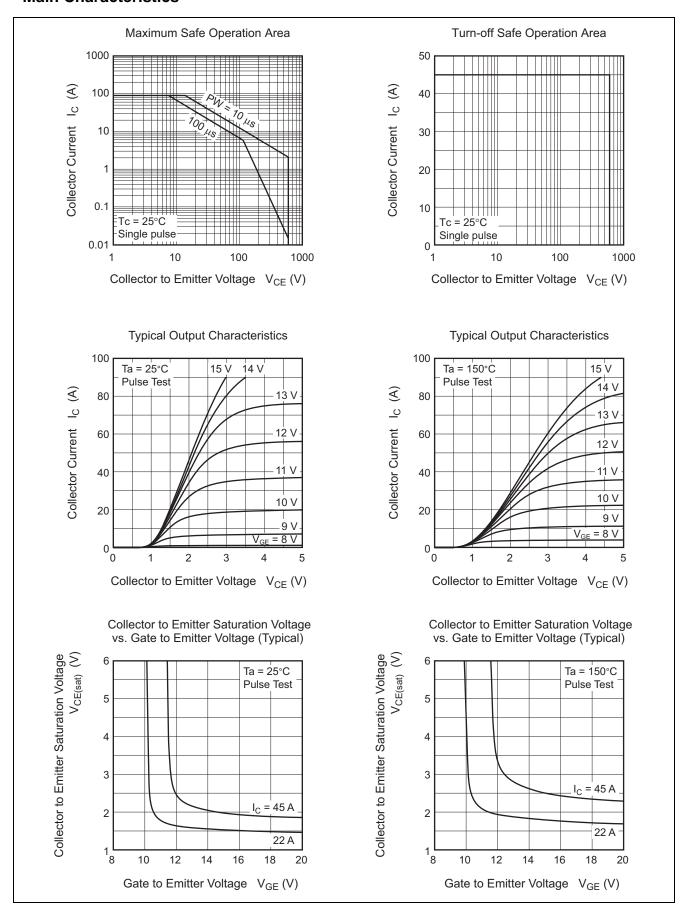
# **Electrical Characteristics**

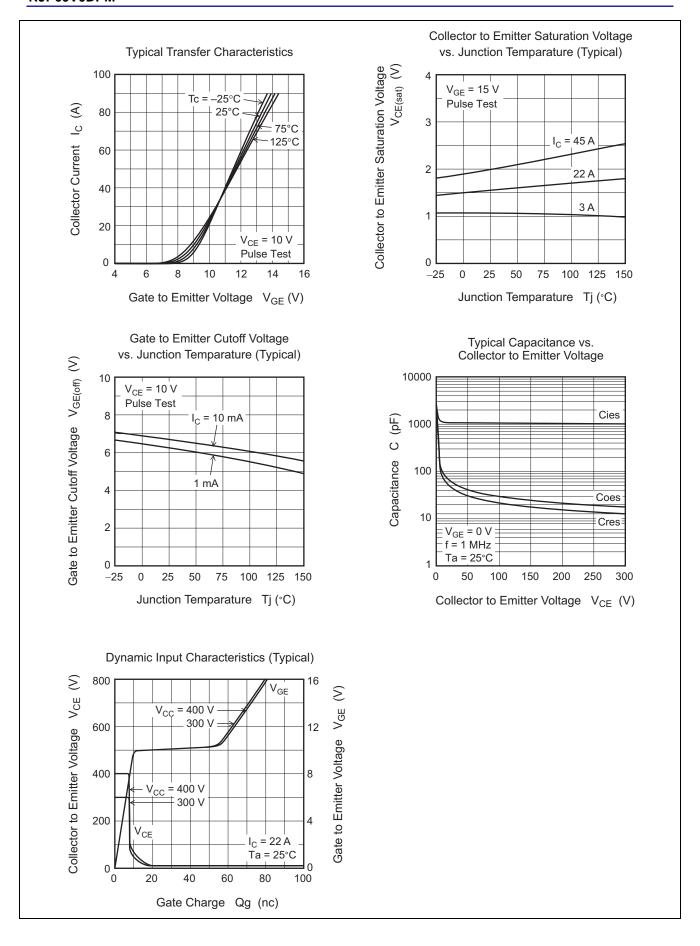
 $(Ta = 25^{\circ}C)$ 

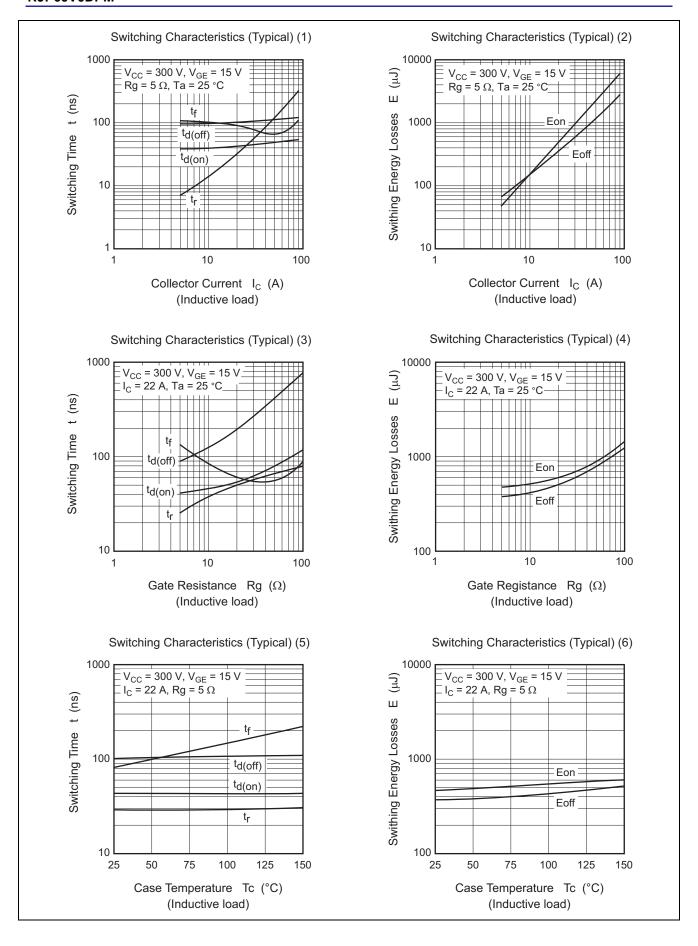
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub>	_	_	1	μΑ	$V_{CE} = 600 \text{ V}, V_{GE} = 0$
Gate to emitter leak current	I <sub>GES</sub>	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	5.5	_	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	1.5	2.1	V	$I_C = 22 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	$V_{CE(sat)}$	_	1.9	_	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	1080	_	pF	$V_{CE} = 25 \text{ V}$ $V_{GE} = 0$ $f = 1 \text{ MHz}$
Output capacitance	Coes	_	58	_	pF	
Reveres transfer capacitance	Cres	_	42	_	pF	
Total gate charge	Qg	_	75	_	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V I <sub>C</sub> = 22 A
Gate to emitter charge	Qge		10	_	nC	
Gate to collector charge	Qgc	_	45	_	nC	
Switching time	t <sub>d(on)</sub>	_	45	_	ns	$V_{CE} = 300 \text{ V} \text{ , } V_{GE} = 15 \text{ V}$ $I_{C} = 22 \text{ A}$ $Rg = 5 \Omega$ Inductive load
	t <sub>r</sub>	_	40	_	ns	
	t <sub>d(off)</sub>	_	100	_	ns	
	<b>t</b> f	_	70	_	ns	
Short circuit withstand time	t <sub>sc</sub>		6	_	μs	$V_{CC} \le 360 \text{ V}$ , $V_{GE} = 15 \text{ V}$ $Tc = 100 ^{\circ}\text{C}$

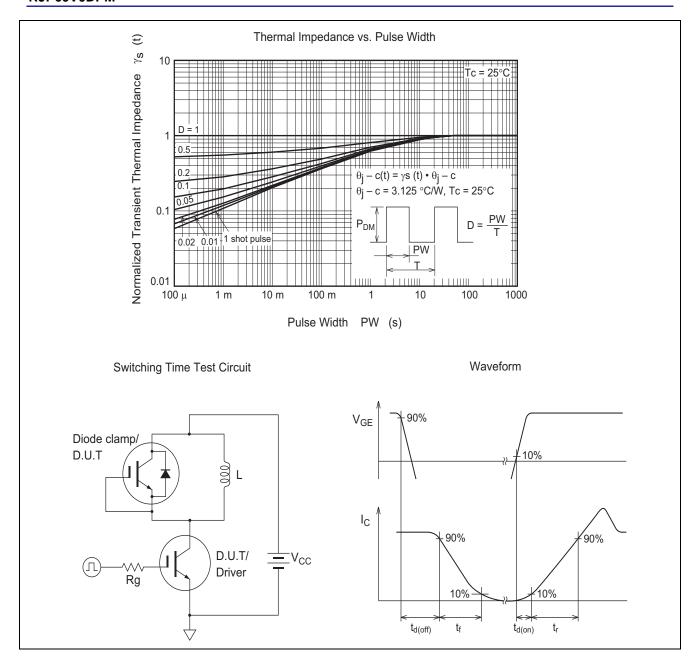
Notes: 3. Pulse test.

### **Main Characteristics**

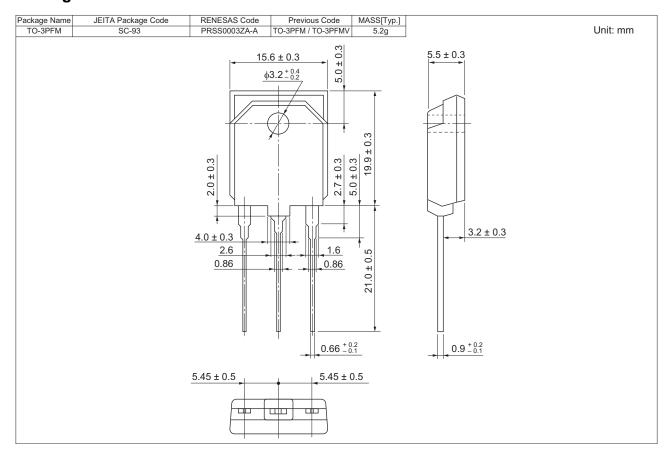








# **Package Dimension**



# **Ordering Information**

Orderable Part No.	Quantity	Shipping Container
RJP60V0DPM-00#T1	360 pcs	Box (Tube)

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Renesas Electronics America Inc. 2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China Tei: +86-10-2035-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 161F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2856-5688, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 105-Tel: +886-2-8175-9600, Fax: +886 2-8175-9670 . ipei 10543, Taiwan

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Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Ku, Seoul, 135-920, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141

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